## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent No	7,160,817 B2
Patent Issue Date	January 9, 2007
Application Serial No	
Filing Date	August 30, 2001
Assignee	Micron Technology, Inc.
Inventorship	Marsh
Attorney's Docket No	Ml22-1728
Title: Dielectric Material Forming Methods a	and Enhanced Dielectric Materials

## REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT FOR APPLICANT MISTAKES and PTO MISTAKES (37 C.F.R. §§ 1.322(a) and 1.323)

To:

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

ATTN:

Decision and Certificate of Correction

Branch of the Patent Issue Division

From:

James E. Lake (Tel. 509-624-4276; Fax 509-838-3424)

Wells St. John P.S.

601 W. First Avenue, Suite 1300

Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 7,160,817 B2, granted January 9, 2007, in accordance with the Certificate of Correction form attached hereto.

It is noted that errors appear in this patent of a typographical nature of character, as more fully described below. The errors occurred in good faith. Correction thereof does not involve such changes in the patent as would constitute new matter or would require re-examination.

Other errors listed on the Certificate of Correction form were apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Attached hereto is Form PTO-1050 being suitable for printing.

The exact page and line number where the errors occur in the application file are:

Paragraph 25, Line 10

Paragraph 28, Line 9

Please charge Deposit Account No. 23-0925 the amount of \$100.00, as required by 37 CFR 1.20(a).

Dated: 31 Jul 2001 By:

Respectfully submitted,

James E. Lake

Reg. No. 44,854

## UNITED STATES PATENT AND TRADEMARK OFFICE

## CERTIFICATE OF CORRECTION

PATENT NO.

: 7,160,817 B2

DATED

: January 9, 2007

INVENTOR(S)

: Marsh

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title (54) — Replace "Dielectric Material Forming Methods" with --Dielectric Material Forming Methods and Enhanced Dielectric Materials--.

Column 4, Line 62 - Replace "greater that of" with --greater than that of--.

Column 5, Line 31 – Replace "approximately evening" with --approximately evenly--.

Column 8, Line 13 – Replace "yield a hdielectric" with --yield a dielectric--.

Page 1 of 1

Mailing Address of Sender:

Wells St. John P.S. 601 West First Avenue, Suite 1300 Spokane, WA 99201-3828 Patent No. 7,160,817 B2